BTA208S series D, E and F

GENERAL DESCRIPTION

QUICK REFERENCE DATA

Passivated guaranteed commutation triacs in a plastic envelope suitable for surface mounting, intended for use in motor control circuits or with other highly inductive loads. These devices balance the requirements of commutation performance and gate sensitivity. The "sensitive gate" E series and "logic level" D series are intended for interfacing with low power drivers, including micro controllers.

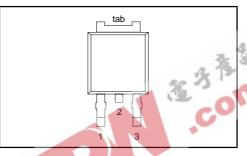
SYMBOL	PARAMETER	MAX.	MAX.	UNIT
	BTA208S- BTA208S- BTA208S-	600D 600E 600F	- 800E 800F	
V_{DRM}	Repetitive peak off-state voltages	600	800	V
I _{T(RMS)} I _{TSM}	RMS on-state current Non-repetitive peak on-state current	8 65	8 65	A A

PINNING - SOT428

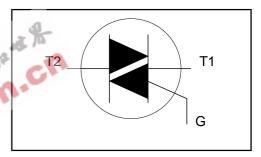
PIN NUMBER	Standard S
1	MT1
2	MT2
3	gate

MT2

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

tab

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MA	X.	UNIT
V_{DRM}	Repetitive peak off-state voltages		-	-600 600 ¹	-800 800	V
I _{T(RMS)}	RMS on-state current	full sine wave;	-	8		Α
I _{TSM}	Non-repetitive peak on-state current	$T_{mb} \le 102 ^{\circ}\text{C}$ full sine wave; $T_{j} = 25 ^{\circ}\text{C}$ prior to surge $t = 20 \text{ms}$ $t = 16.7 \text{ms}$	-	65 72		A A
l²t dl _⊤ /dt	l ² t for fusing Repetitive rate of rise of on-state current after	t = 10.7 ms t = 10 ms $I_{TM} = 12 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu\text{s}$	-	21	1	Α ² s Α/μs
I _{GM} V _{GM} P _{GM} P _{G(AV)}	triggering Peak gate current Peak gate voltage Peak gate power Average gate power	over any 20 ms period	-	2 5 5 0.:		A V W W
$T_{stg} \\ T_{j}$	Storage temperature Operating junction temperature	, polica	-40 -	150 125		°C

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¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 6 $A/\mu s$.

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{\text{th } j\text{-mb}}$ $R_{\text{th } j\text{-a}}$	Thermal resistance junction to mounting base Thermal resistance junction to ambient	full cycle half cycle pcb (FR4) mounted; footprint as in Fig.14		- - 75	2.0 2.4 -	K/W K/W K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER CONDITIONS MIN. TYP. MAX.			UNIT				
		BTA208S-			D	Е	F	
I _{GT}	Gate trigger current ²	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}$ T2 + G + T2 + G - T2 - G -	-		5 5 5	10 10 10	25 25 25	mA mA mA
I _L	Latching current	V _D = 12 V; I _{GT} = 0.1 A T2+ G+ T2+ G- T2- G-	OW.	.CV	15 25 25	20 30 30	25 40 40	mA mA mA
I _H	Holding current	$V_D = 12 \text{ V}; I_{GT} = 0.1 \text{ A}$	-	-	15	25	30	mA
V_{T} V_{GT}	On-state voltage Gate trigger voltage	$I_T = 10 \text{ A}$ $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}$ $V_D = 400 \text{ V}; I_T = 0.1 \text{ A};$ $I_T = 125 \text{ °C}$	- - 0.25	1.3 0.7 0.4		1.65 1.5 -		V V V
I _D	Off-state leakage current	$V_D = V_{DRM(max)};$ $T_i = 125 °C$	-	0.1		0.5		mA

DYNAMIC CHARACTERISTICS

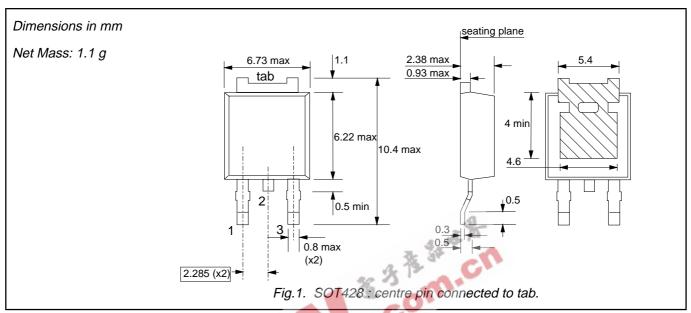
 $T_j = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.		TYP.	MAX.	UNIT	
		BTA208S-	D	Е	F			
dV _D /dt	Critical rate of rise of off-state voltage	V _{DM} = 67% V _{DRM(max)} ; T _j = 110 °C; exponential waveform; gate open circuit	30	60	70		-	V/μs
dl _{com} /dt	Critical rate of change of commutating current	$V_{DM} = 400 \text{ V}; T_j = 110 ^{\circ}\text{C};$ $I_{T(RMS)} = 8 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu\text{s}; \text{ gate}$ open circuit	1.8	3.5	4.5		-	A/ms
dl _{com} /dt	Critical rate of change of commutating current	$ \begin{vmatrix} V_{\text{DM}} = 400 \text{ V; T}_{j} = 110 \text{ °C;} \\ I_{\text{T(RMS)}} = 8 \text{ A;} \\ dV_{\text{com}}/dt = 0.1 \text{v/}\mu\text{s; gate} \\ \text{open circuit} $	3.5	4.5	5.5		-	A/ms
t _{gt}	Gate controlled turn-on time	$I_{TM} = 12 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A/}\mu s$	-	-	-	2	-	μs

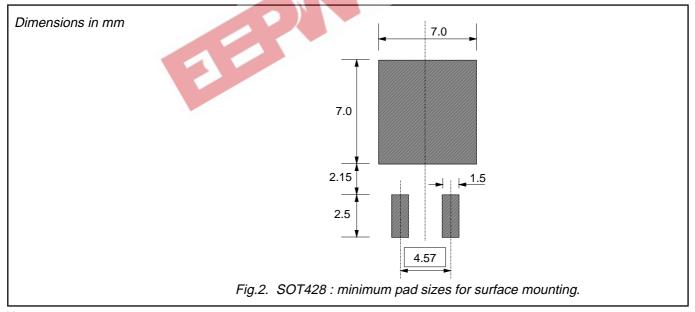
² Device does not trigger in the T2-, G+ quadrant.

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MECHANICAL DATA



MOUNTING INSTRUCTIONS



Notes

1. Plastic meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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